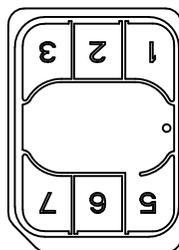


Nano SIM Circuit Description:

PIN No.	FUNCTION
C1	VCC
C2	RST
C3	CLK
C5	GND
C6	VPP
C7	I/O



RECOMMENDED P.C.B LAYOUT COMPONENT SIDE(TOLERANCE ±0.05)

- PAD AREA
- CONNECTOR DUTLINE/END
- PATTERN
- AN DIAHOLE IN THIS AREA

TECHNICAL CHARACTERISTICS1.

- 1.General Characteristics
 Dimensions:12.40LX9.80WX1.35H mm
 Weight: Approx 0.50±0.2g
 Durability:1,500cycles min.
- 2.Electrical Characteristics
 Contact resistance:50mΩ typical,
 100m. max
 Insulation resistance:>1000M0/500V DC
 Solderability
 Vaporphase:215°C,30sec.MaxIR
 reflow:250C,5sec.MaxManual soldering:370°C,3sec.Max
- 4.Environmental Characteristics
 Operating temperature:-40°C~+85°C
 Operating humidity:10%~+95%RH

3	CONTACT	1	COPPER ALLOY	CONTACT AREA:GOLD PLATED
2	SHELL	1	STAINLESS STEEL	
1	HOUSING	1	LCP UL94V-0	COLOR:BLACK
NO.	DESCRIPTION	Q'TY	Material	Finish



深圳市华宇创精密电子有限公司

TOLERANCE: X.X ±0.30 X.XX ±0.25 X.XXX ±0.15 X' ±2' X.X' ±0.5'	DRAWN BY : 陈一鸣	DATE : 2014-02-23	PART NAME: NANO SIM 6P 1.32H 带检测P 脚向外
	CHECKED BY: 马跃	DATE : 2014-02-23	PART NO. HVC384-SIM07-132
UNIT: mm [inch] SCALE:1:1 SIZE: A4	APPROVED BY: 邱敏	DATE : 2014-02-23	DRAW NO: HVC-2602281018
			SHEET NO. 1 OF 1